

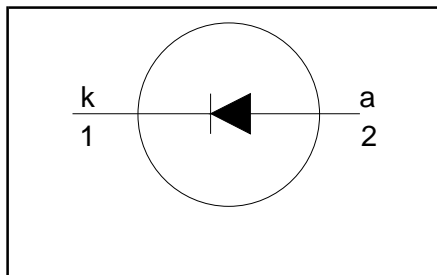
**Rectifier diodes  
ultrafast**

**BYR29F series**

**FEATURES**

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Isolated mounting tab

**SYMBOL**



**QUICK REFERENCE DATA**

$V_R = 500\text{ V} / 600\text{ V} / 700\text{ V} / 800\text{ V}$
$V_F \leq 1.5\text{ V}$
$I_{F(AV)} = 8\text{ A}$
$t_{rr} \leq 75\text{ ns}$

**GENERAL DESCRIPTION**

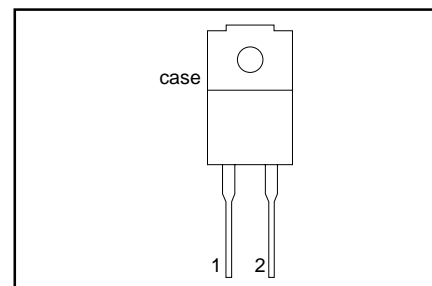
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYR29F series is supplied in the conventional leaded SOD100 package.

**PINNING**

PIN	DESCRIPTION
1	cathode
2	anode
tab	isolated

**SOD100**



**LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.				UNIT
				-500	-600	-700	-800	
$V_{RRM}$	Peak repetitive reverse voltage	BYR29F $T_{hs} \leq 136\text{ }^\circ\text{C}$	-	500	600	700	800	V
$V_{RWM}$	Crest working reverse voltage		-	500	600	700	800	V
$V_R$	Continuous reverse voltage		-	500	600	700	800	V
$I_{F(AV)}$	Average forward current <sup>1</sup>	square wave; $\delta = 0.5$ ; $T_{hs} \leq 73\text{ }^\circ\text{C}$	-	8				A
$I_{FRM}$	Repetitive peak forward current	$t = 25\text{ }\mu\text{s}$ ; $\delta = 0.5$ ; $T_{hs} \leq 73\text{ }^\circ\text{C}$	-	16				A
$I_{FSM}$	Non-repetitive peak forward current	$t = 10\text{ ms}$	-	60				A
		$t = 8.3\text{ ms}$	-	66				A
$T_{stg}$	Storage temperature	sinusoidal; with reapplied $V_{RRM(max)}$	-40	150				$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150				$^\circ\text{C}$

<sup>1</sup> Neglecting switching and reverse current losses

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**ISOLATION LIMITING VALUE & CHARACTERISTIC** $T_{hs} = 25\text{ °C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{isol}$	Repetitive peak voltage from both terminals to external heatsink	R.H. $\leq$ 65% ; clean and dustfree	-		1500	V
$C_{isol}$	Capacitance from cathode to external heatsink	$f = 1\text{ MHz}$	-	12	-	pF

**THERMAL RESISTANCES**

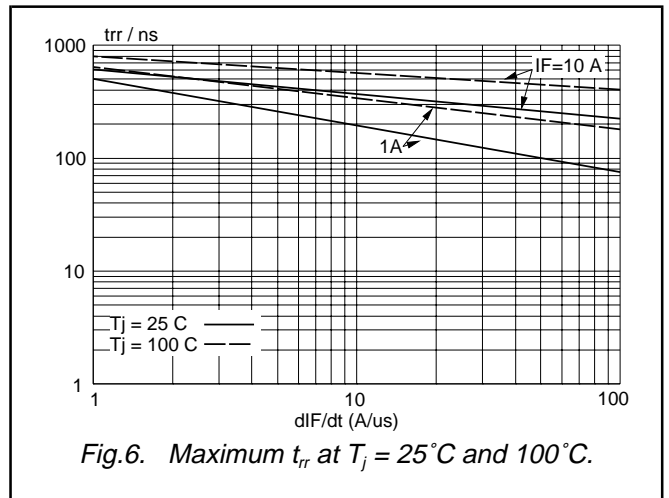
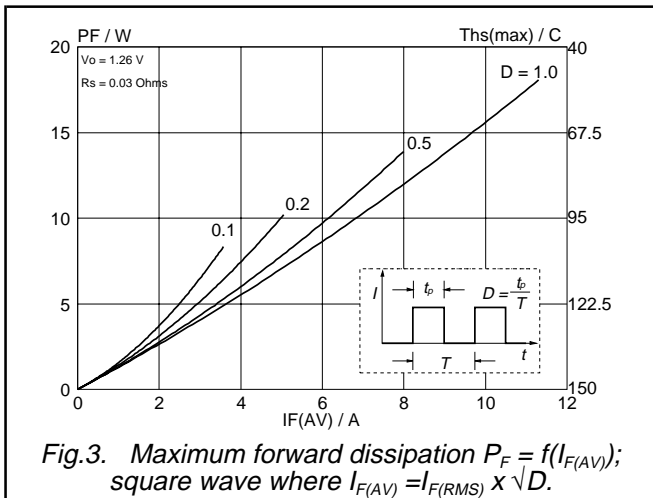
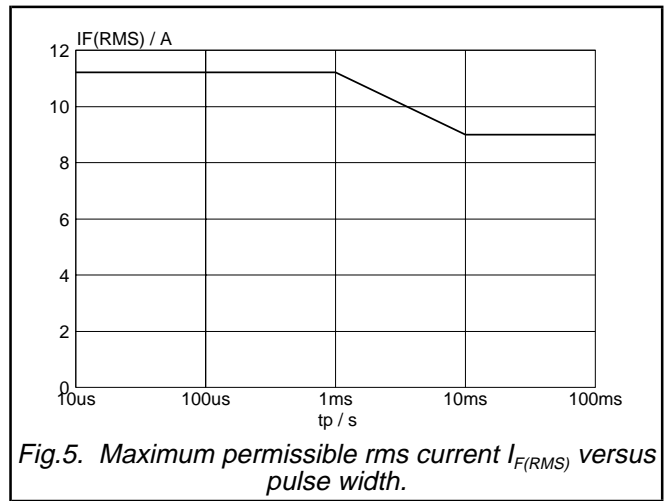
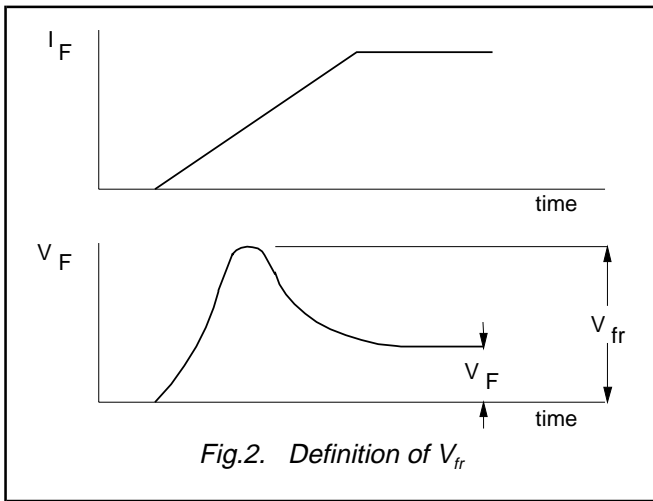
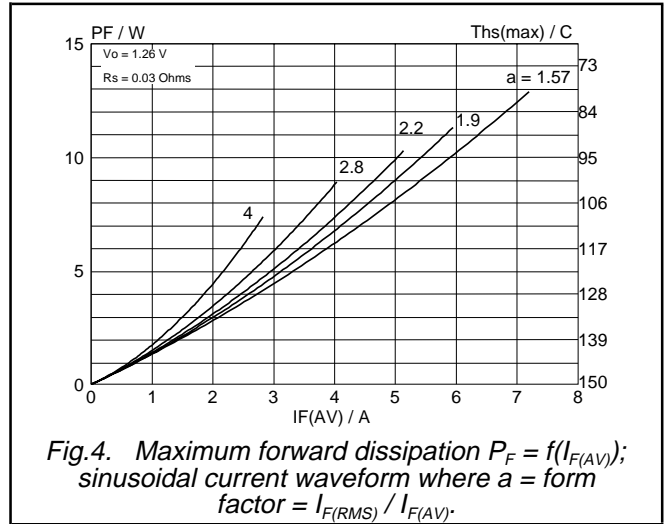
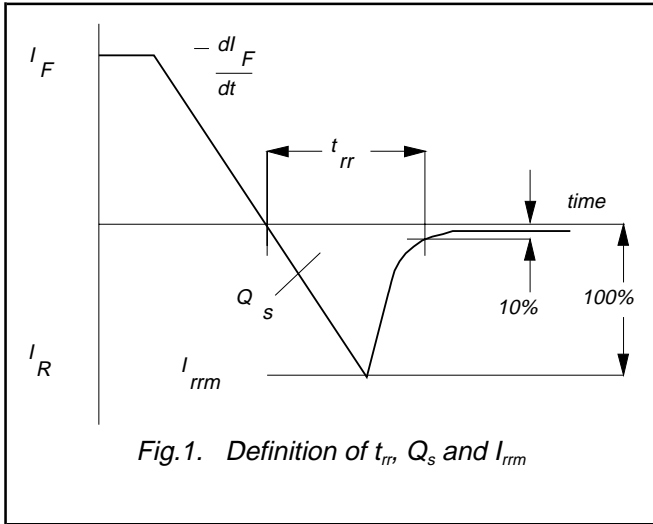
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-hs}$	Thermal resistance junction to heatsink	with heatsink compound	-	-	5.5	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	without heatsink compound in free air.	-	55	7.2	K/W

**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ °C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 8\text{ A}$ ; $T_j = 150\text{ °C}$	-	1.07	1.50	V
		$I_F = 20\text{ A}$	-	1.75	1.95	V
$I_R$	Reverse current	$V_R = V_{RRM}$	-	1.0	10	$\mu\text{A}$
		$V_R = V_{RRM}$ ; $T_j = 100\text{ °C}$	-	0.1	0.2	mA
$Q_s$	Reverse recovery charge	$I_F = 2\text{ A}$ to $V_R \geq 30\text{ V}$ ; $di_F/dt = 20\text{ A}/\mu\text{s}$	-	150	200	nC
$t_{rr}$	Reverse recovery time	$I_F = 1\text{ A}$ to $V_R \geq 30\text{ V}$ ; $di_F/dt = 100\text{ A}/\mu\text{s}$	-	60	75	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 10\text{ A}$ to $V_R \geq 30\text{ V}$ ; $di_F/dt = 50\text{ A}/\mu\text{s}$ ; $T_j = 100\text{ °C}$	-	-	6	A
$V_{fr}$	Forward recovery voltage	$I_F = 10\text{ A}$ ; $di_F/dt = 10\text{ A}/\mu\text{s}$	-	5.0	-	V

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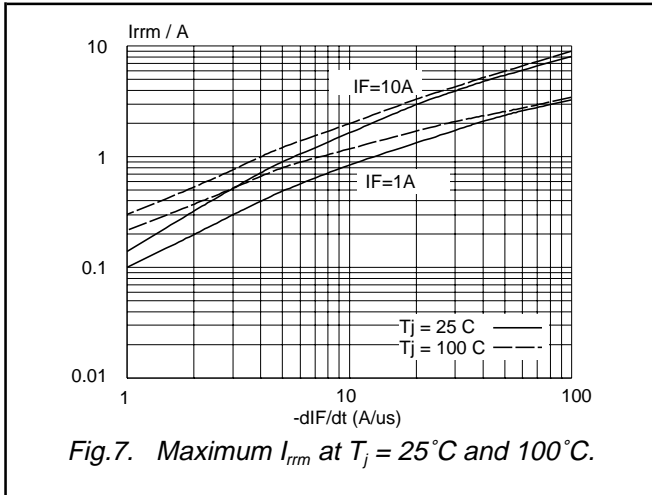


Fig.7. Maximum  $I_{rrm}$  at  $T_j = 25^\circ C$  and  $100^\circ C$ .

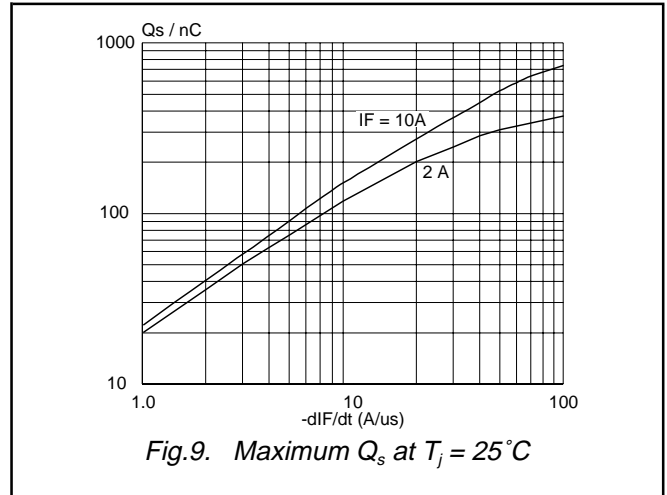


Fig.9. Maximum  $Q_s$  at  $T_j = 25^\circ C$

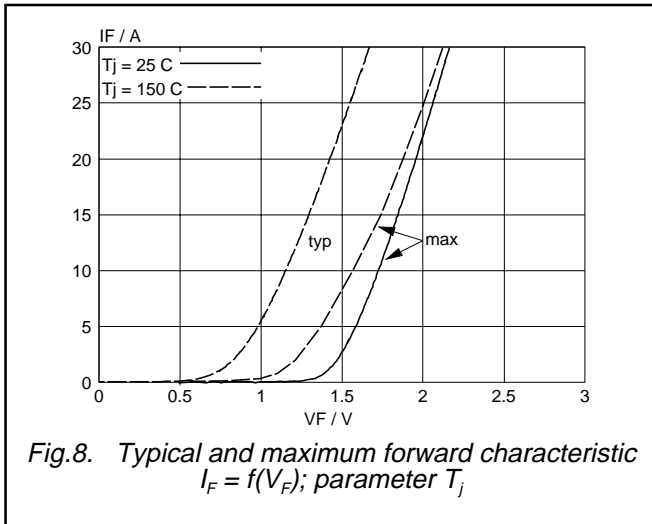


Fig.8. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$

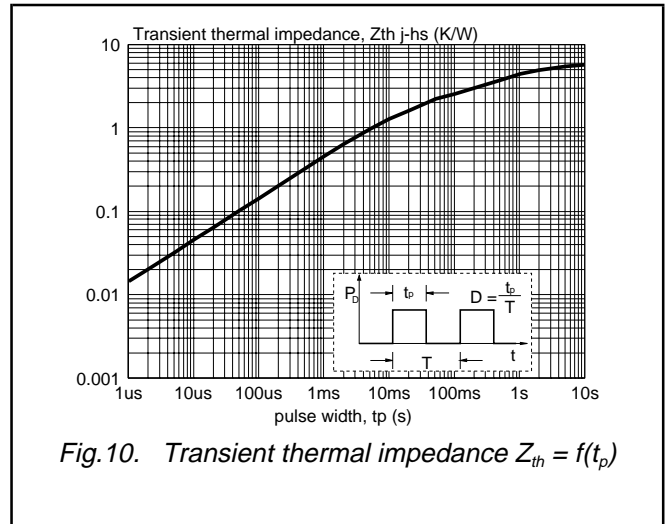
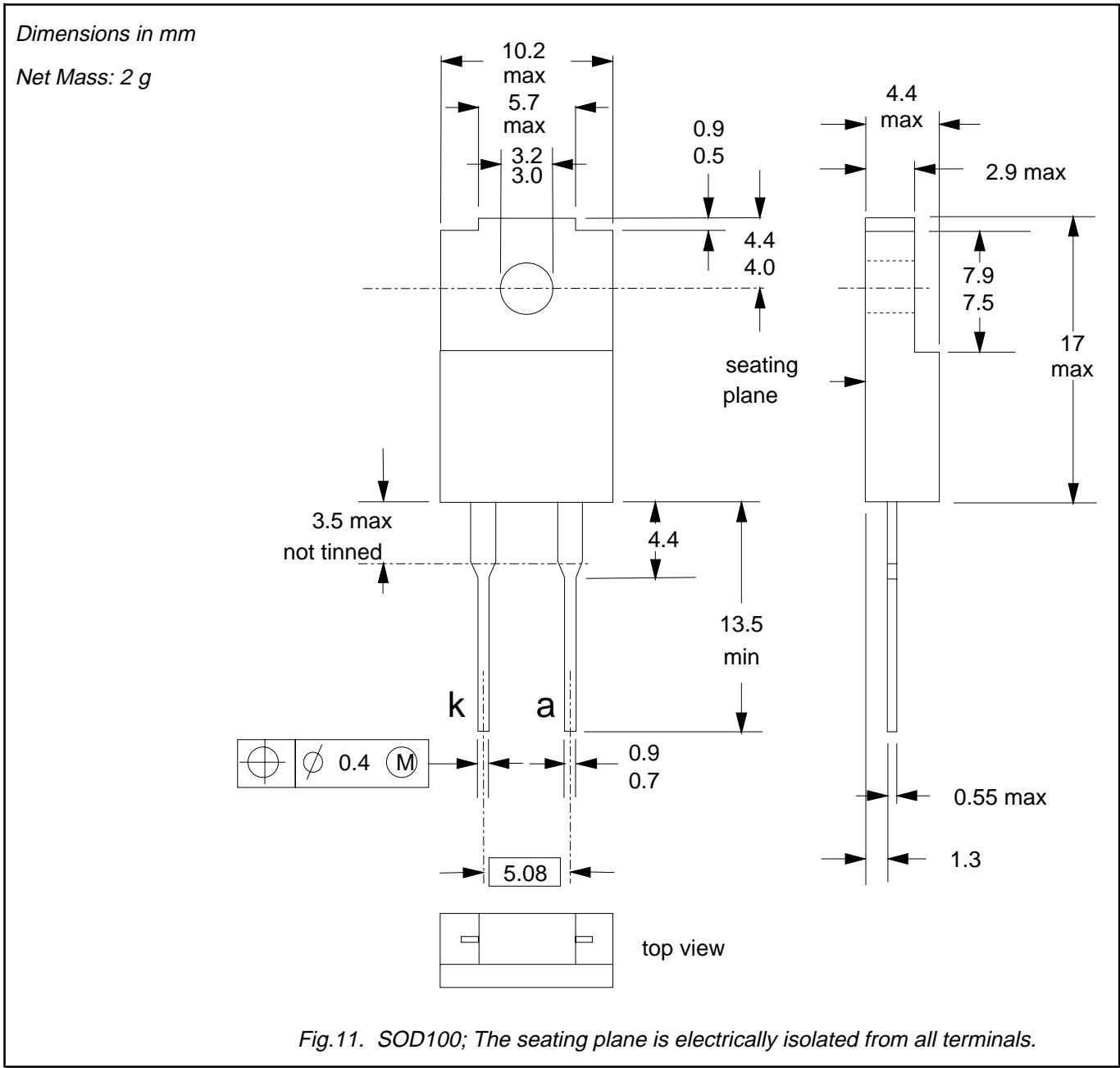


Fig.10. Transient thermal impedance  $Z_{th} = f(t_p)$

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**MECHANICAL DATA**



**Notes**

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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**BYR29F series****DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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